Very Low Forward Voltage Trench-based Schottky Rectifier

Exceptionally Low $V_F = 0.455$ V at $I_F = 5$ A

Features

- Fine Lithography Trench–based Schottky Technology for Very Low Forward Voltage and Low Leakage
- Fast Switching with Exceptional Temperature Stability
- Low Power Loss and Lower Operating Temperature
- Higher Efficiency for Achieving Regulatory Compliance
- Low Thermal Resistance
- High Surge Capability
- Pb-Free and Halide-Free Packages are Available

Typical Applications

- Switching Power Supplies including Notebook / Netbook Adapters, ATX and Flat Panel Display
- High Frequency and DC–DC Converters
- Freewheeling and OR-ing diodes
- Reverse Battery Protection
- Instrumentation

Mechanical Characteristics

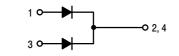
- Case: Epoxy, Molded
- Epoxy Meets Flammability Rating UL 94-0 @ 0.125 in
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Maximum for 10 sec

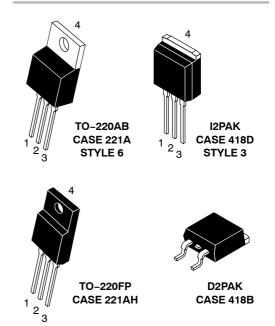


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PIN CONNECTIONS





ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

1

MAXIMUM RATINGS

Rating		Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage		V _{RRM} V _{RWM} V _R	100	V
Average Rectified Forward Current (Rated V_R , T_C = 115°C)	Per device Per diode	I _{F(AV)}	30 15	A
Peak Repetitive Forward Current (Rated V _R , Square Wave, 20 kHz, T _C = 110°C)	Per device Per diode	I _{FRM}	60 30	A
Nonrepetitive Peak Surge Current (Surge applied at rated load conditions halfwave, single phase, 60 Hz)		I _{FSM}	160	A
Operating Junction Temperature		TJ	-40 to +150	°C
Storage Temperature		T _{stg}	-40 to +150	°C
Voltage Rate of Change (Rated V _R)		dv/dt	10,000	V/μs

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

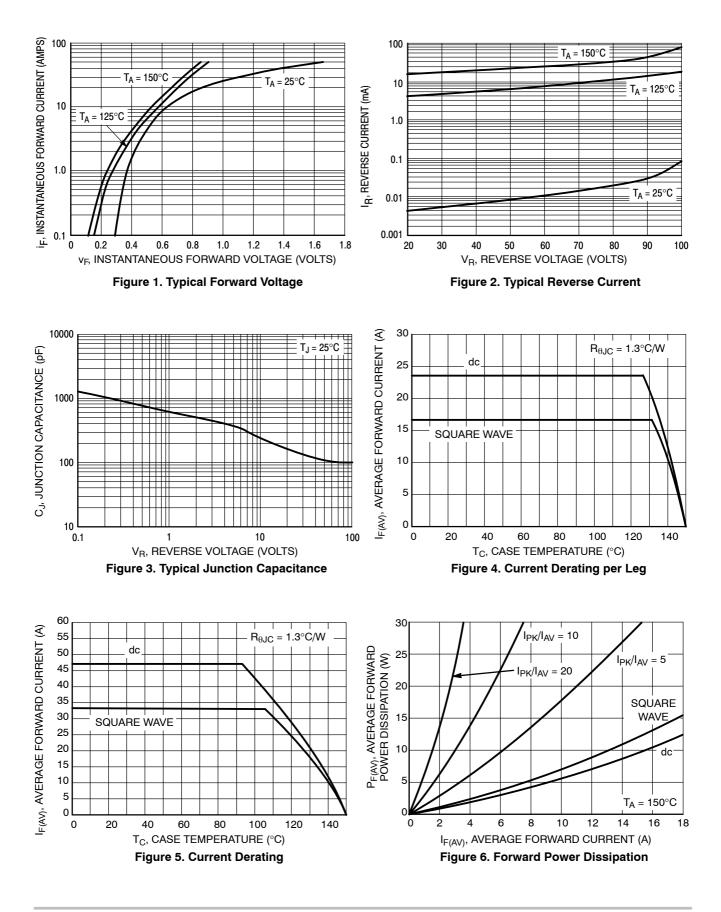
THERMAL CHARACTERISTICS

Rating	Symbol	NTST30100CTG, NTSB30100CT-1G	NTSB30100CTG	NTSJ30100CTG	Unit
Maximum Thermal Resistance per Diode Junction-to-Case Junction-to-Ambient	000	2.5 70	1.14 46.6	4.09 105	°C/W °C/W

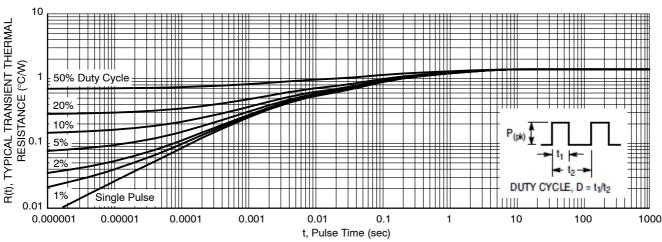
ELECTRICAL CHARACTERISTICS (Per Leg unless otherwise noted)

Rating	Symbol	Тур	Мах	Unit
	۷F	0.516 0.576 0.734	- - 0.85	V
$(I_F = 5 A, T_J = 125^{\circ}C)$ $(I_F = 7.5 A, T_J = 125^{\circ}C)$ $(I_F = 15 A, T_J = 125^{\circ}C)$		0.455 0.522 0.627	_ _ 0.68	
Maximum Instantaneous Reverse Current (Note 1) $(V_R = 70 \text{ V}, T_J = 25^{\circ}\text{C})$ $(V_R = 70 \text{ V}, T_J = 125^{\circ}\text{C})$	I _R	7.2 8.0		μA mA
(Rated dc Voltage, $T_J = 25^{\circ}C$) (Rated dc Voltage, $T_J = 125^{\circ}C$)		65 20	500 35	μA mA

1. Pulse Test: Pulse Width = 300 $\mu s,$ Duty Cycle $\,\leq\,$ 2.0%



TYPICAL CHARACTERISITICS



TYPICAL CHARACTERISITICS

Figure 7. Typical Transient Thermal Response, Junction-to-Case for NTST30100CT and NTSB30100CT-1G

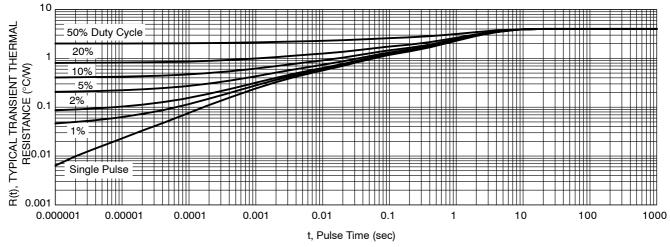
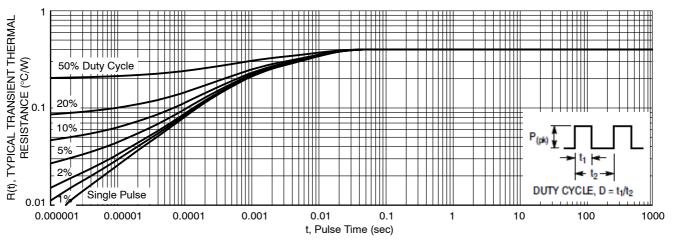


Figure 8. Typical Transient Thermal Response, Junction-to-Case for NTSJ30100CTG

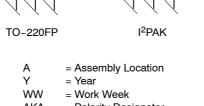




ORDERING INFORMATION

Device	Package	Shipping	
NTST30100CTG	TO-220AB (Pb-Free)	50 Units / Rail	
NTSB30100CT-1G	l ² PAK (Pb–Free)	50 Units / Rail	
NTSJ30100CTG	TO-220FP (Halide-Free)	50 Units / Rail	
NTSB30100CTG	D ² PAK (Pb–Free)	50 Units / Rail	
NTSB30100CTT4G	D ² PAK (Pb–Free)	800 / Tape & Reel	

AYWW AYWW TS30100CG AYWW AYWW TS30100CG TS30100Cx TS30100CG AKA AKA AKA AKA TO-220FP I²PAK D²PAK TO-220AB

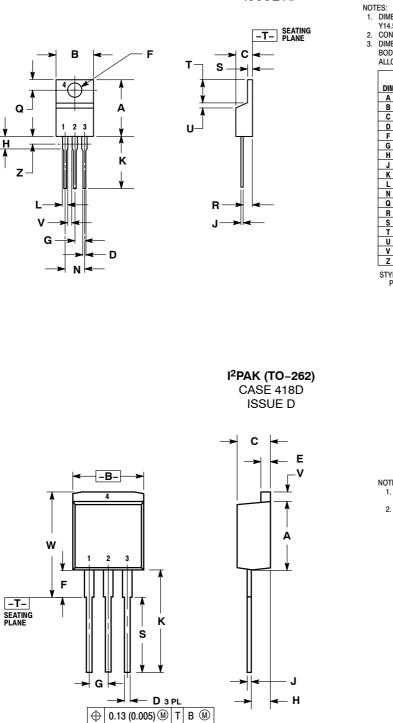


- AKA = Polarity Designator
- х = G or H
- G = Pb-Free Package
- Н = Halide-Free Package

MARKING DIAGRAMS

PACKAGE DIMENSIONS

TO-220 CASE 221A-09 **ISSUE AF**



DIMENSIONING AND TOLERANCING PER ANSI 914.5M, 1982. CONTROLLING DIMENSION: INCH. DIMENSION 2 DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

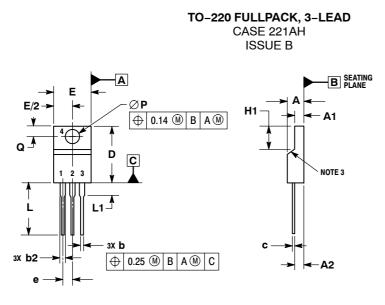
	INC	HES	MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.570	0.620	14.48	15.75	
В	0.380	0.405	9.66	10.28	
С	0.160	0.190	4.07	4.82	
D	0.025	0.035	0.64	0.88	
F	0.142	0.161	3.61	4.09	
G	0.095	0.105	2.42	2.66	
Н	0.110	0.155	2.80	3.93	
J	0.014	0.025	0.36	0.64	
ĸ	0.500	0.562	12.70	14.27	
L	0.045	0.060	1.15	1.52	
Ν	0.190	0.210	4.83	5.33	
Q	0.100	0.120	2.54	3.04	
R	0.080	0.110	2.04	2.79	
S	0.045	0.055	1.15	1.39	
T	0.235	0.255	5.97	6.47	
U	0.000	0.050	0.00	1.27	
۷	0.045		1.15		
Z		0.080		2.04	
STYLE 6: PIN 1. ANODE					
	2. CAT	HODE			

CATHODE 4.

NOTES: DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
CONTROLLING DIMENSION: INCH.

	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.335	0.380	8.51	9.65
В	0.380	0.406	9.65	10.31
С	0.160	0.185	4.06	4.70
D	0.026	0.035	0.66	0.89
Е	0.045	0.055	1.14	1.40
F	0.122 REF		3.10 REF	
G	0.100	BSC	2.54	BSC
н	0.094	0.110	2.39	2.79
J	0.013	0.025	0.33	0.64
K	0.500	0.562	12.70	14.27
S	0.390 REF		9.90	REF
٧	0.045	0.070	1.14	1.78
W	0.522	0.551	13.25	14.00

PACKAGE DIMENSIONS



NOTES:

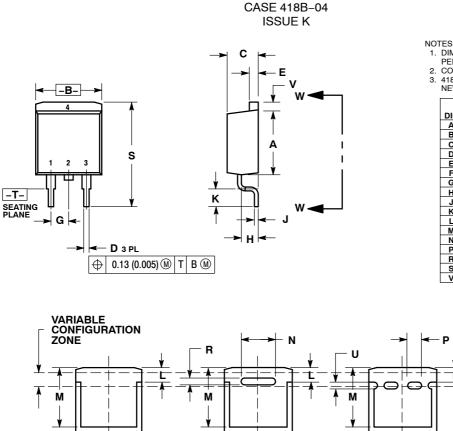
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.

Y14.5M, 1994. 2. CONTROLLING DIMENSION: MILLIMETERS. 3. CONTOUL UNCONTROLLED IN THIS AREA. 4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH AND GATE PROTRUSIONS. MOLD FLASH AND GATE PROTRUSIONS NOT TO EXCEED 0.13 PER SIDE. THESE DIMENSIONS ARE TO BE MEASURED AT OUTERMOST EXTREME OF THE PLASTIC BODY. 5. DIMENSION b2 DOES NOT INCLUDE DAMBAR PROTRUSION. LEAD WIDTH INCLUDING PROTRUSION SHALL NOT EXCEED 2.00.

	SHALL NOT EXCEED 2.0				
	MILLIMETERS				
DIM	MIN MAX				
Α	4.30	4.70			
A1	2.50	2.90			
A2	2.50	2.70			
b	0.54	0.84			
b2	1.10	1.40			
C	0.49	0.79			
D	14.70	15.30			
Е	9.70	10.30			
е	2.54 BSC				
H1	6.70	7.10			
L	12.70	14.73			
L1		2.80			
Ρ	3.00	3.40			
Q	2.80	3.20			

PACKAGE DIMENSIONS

D²PAK 3

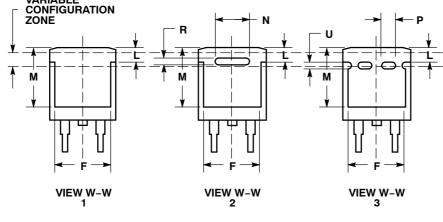


1. DIMENSIONING AND TOLERANCING PER ANSI V14 5M 1982

PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH. 3. 418B-01 THRU 418B-03 OBSOLETE

418B-01 THRU 418B-03 OBSOLETE, NEW STANDARD 418B-04.

	INCHES		INCHES MIL		MILLIN	LLIMETERS	
DIM	MIN	MAX	MIN	MAX			
Α	0.340	0.380	8.64	9.65			
в	0.380	0.405	9.65	10.29			
С	0.160	0.190	4.06	4.83			
D	0.020	0.035	0.51	0.89			
Е	0.045	0.055	1.14	1.40			
F	0.310	0.350	7.87	8.89			
G	0.100 BSC		2.54 BSC				
Н	0.080	0.110	2.03	2.79			
J	0.018	0.025	0.46	0.64			
ĸ	0.090	0.110	2.29	2.79			
L	0.052	0.072	1.32	1.83			
м	0.280	0.320	7.11	8.13			
N	0.197 REF		5.00 REF				
Р	0.079 REF		2.00 REF				
R	0.039	REF	0.99 REF				
S	0.575	0.625	14.60	15.88			
V	0.045	0.055	1.14	1.40			



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